# MW39962AE

# Diagonal 11 mm (type-2/3) FIT CCD Area Image Sensor

### Overview

The MW39962AE is a type-2/3 2.2M-pixel frame interline transfer (FIT-CCD) solid state image sensor.

This device uses photodiodes in the opto-electric conversion section and CCDs for signal read-out. The electronic shutter function allows for an exposure time of 1/10000 seconds. Further, it features high sensitivity, low noise, broad dynamic range and low smear level.

The device has a total of 2182860 pixels (2010 horizontal  $\times$  1086 vertical) and provides stable and clear images with a resolution of 1100 horizontal and 730 vertical TV lines.

Part Number	CCD size	System	Color or B/W
MW39962AE	11 mm (type-2/3)	HDTV	B/W

#### Features

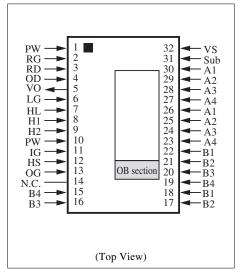
- Effective pixel number: 1936 (horizontal) × 1086 (vertical)
- High sensitivity
- High resolution
- Low smear level
- · Continuously variable-speed electronic shutter function
- Frame interline transfer system

### Applications

www.DBroadcasting and professional use camera

• Front-edge surveillance camera

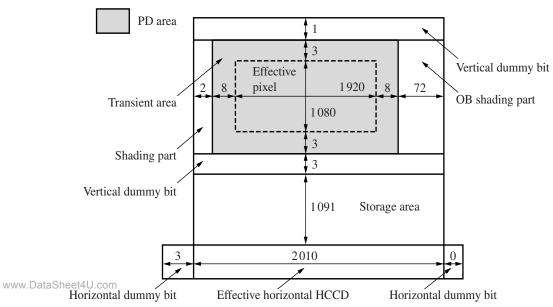
#### Pin Assignments



#### Device Configuration

Parameter	Value	Unit
Horizontal drive frequency	$f_{CK} = 2200  f_H = 74.25$	MHz
Total pixel number	2010 (H) × 1086 (V)	Pixel
Effective pixel number (including transient ones)	1936 (H) × 1086 (V)	Pixel
Effective pixel number	1920 (H) × 1080 (V)	Pixel
Pixel size	5.0 (H) × 5.0 (V)	μm <sup>2</sup>
Effective image sensor size	9.6 (H) × 5.4 (V)	mm <sup>2</sup>
Aspect ratio	16:9	H : V
Aspect ration error	0.0	%

#### • Element Construction



Note) The horizontal dummy bit is based on 2 gates = 1 unit.

### Pin Descriptions

Pin No.	Symbol	Description	Pin No.	Symbol	Description
1	PW	P-well	11	IG	Horizontal input gate
2	RG	Reset gate	12	HS	Horizontal input source
3	RD	Reset drain	13	OG	Output gate
4	OD	Output drain	14	N.C.	Non Connection
5	VO	Video output	15	B4	Storage area vertical CCD gate 4
6	LG	Output load transistor gate	16	B3	Storage area vertical CCD gate 3
7	HL	Horizontal CCD final gate	17	B2	Storage area vertical CCD gate 2
8	H1	Horizontal CCD gate 1	18	B1	Storage area vertical CCD gate 1
9	H2	Horizontal CCD gate 2	19	B4	Storage area vertical CCD gate 4
10	PW	P-well	20	B3	Storage area vertical CCD gate 3

## ■ Pin Descriptions (continued)

Pin No.	Symbol	Description	Pin No.	Symbol	Description
21	B2	Storage area vertical CCD gate 2	27	A4	Sensor area vertical CCD gate 4
22	B1	Storage area vertical CCD gate 1	28	A3	Sensor area vertical CCD gate 3
23	A4	Sensor area vertical CCD gate 4	29	A2	Sensor area vertical CCD gate 2
24	A3	Sensor area vertical CCD gate 3	30	A1	Sensor area vertical CCD gate 1
25	A2	Sensor area vertical CCD gate 2	31	Sub	Substrate
26	A1	Sensor area vertical CCD gate 1	32	VS	Vertical input source

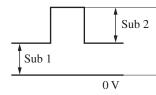
## Absolute Maximum Ratings and Operating Conditions

	Parameter		Absolute maximum rating		Op	Operating condition		
Pin No.	Para	neter	Lower limit Upper limit		Min	Тур	Max	Unit
1	PW		Referenc	Reference voltage		0.0		V
2	RG	Amplitude	0	9.0	4.7	5.0	5.3	V
		Low	0		1.0	adj.	8.0	V
3	RD		0	18	14.3	14.5	14.7	V
4	OD		0	18	14.3	14.5	14.7	V
5	VO		_					V
6	LG		0	6	1.0	adj.	4.0	V
7	φ <sub>HL</sub>	High		10	2.7	3.0	3.3	V
		Low	0		0.0	0.0	0.3	V
8	ф <sub>Н1</sub>	High		10	2.7	3.0	3.3	V
		Low	0		0.0	0.0	0.3	V
9	ф <sub>H2</sub>	High		10	2.7	3.0	3.3	V
		Low	0		0.0	0.0	0.3	V
vww.DataShe	/.DataSheet411.com		Referenc	e voltage		0.0		V
11	IG		0	5		0.0		V
12	HS		0	18	15.7	16.0	16.3	V
13	OG		0	5	0.0	adj.	0.3	V
14	N.C.							
15	$\phi_{\rm B4}$	Middle		18	- 0.3	0.0	0.3	V
		Low	-12	_	-9.3	-9.0	-8.7	V
16	<b>ф</b> <sub>В3</sub>	Middle		18	- 0.3	0.0	0.3	V
		Low	-12		-9.3	-9.0	-8.7	V
17	φ <sub>B2</sub>	Middle		18	- 0.3	0	0.3	V
		Low	-12		-9.3	-9.0	-8.7	V
18	$\phi_{B1}$	Middle		18	- 0.3	0.0	0.3	V
		Low	-12		-9.3	-9.0	-8.7	V
19	$\phi_{\rm B4}$	Middle		18	- 0.3	0.0	0.3	V
		Low	-12		-9.3	-9.0	-8.7	v

## Absolute Maximum Ratings and Operating Conditions (continued)

	Parameter		Absolute maximum rating		Operating condition			
Pin No.	Parai	meter	Lower limit	Upper limit	Min	Тур	Max	– Uni
20	φ <sub>B3</sub>	Middle	_	18	- 0.3	0.0	0.3	V
		Low	-12		-9.3	-9.0	-8.7	V
21	$\phi_{B2}$	Middle	_	18	- 0.3	0.0	0.3	V
		Low	-12		-9.3	-9.0	-8.7	V
22	$\phi_{B1}$	Middle	_	18	- 0.3	0.0	0.3	V
		Low	-12		-9.3	-9.0	-8.7	V
23	$\phi_{A4}$	Middle	_	18	- 0.3	0.0	0.3	V
		Low	-12		-8.3	-8.0	-7.7	V
24	$\phi_{A3}$	High	—	18	14.7	15.0	15.3	V
		Middle	_	18	- 0.3	0.0	0.3	V
		Low	-12		-8.3	-8.0	-7.7	V
25	$\phi_{A2}$	Middle	—	18	0.7	1.0	1.3	V
		Low	-12		-8.3	-8.0	-7.7	V
26	$\phi_{A1}$	High	_	18	14.7	15.0	15.3	V
		Middle	_	18	- 0.3	0.0	0.3	V
		Low	-12		-8.3	-8.0	-7.7	V
27	$\phi_{A4}$	Middle	—	18	- 0.3	0.0	0.3	V
		Low	-12		-8.3	-8.0	-7.7	V
28	\$\$A3	High	_	18	14.7	15.0	15.3	V
		Middle	—	18	- 0.3	0.0	0.3	V
		Low	-12		-8.3	-8.0	-7.7	V
.Da <mark>29</mark> She	et40.2com	Middle	_	18	0.7	1.0	1.3	V
		Low	-12		-8.3	-8.0	-7.7	V
30	$\phi_{A1}$	High	—	18	14.7	15.0	15.3	V
		Middle	—	18	- 0.3	0	0.3	V
		Low	-12	—	-8.3	-8.0	-7.7	V
31 Sub	Sub *1	1	0	40 *2	3.0	adj.	14.0	V
		2	0	40	24.0	25.0	26.0	V
32	VS		0	18	15.7	16.0	16.3	V
Operati	ng temperatur	re	-10	60	_	25		°C
Storage	Storage temperature		-30	70				°C

Note) \*1 : Sub pulse at the electronic shutter



 $\ast 2$  : Upper limit of Sub maximum rating:

Sub 1 + Sub  $2 \le 40$  V

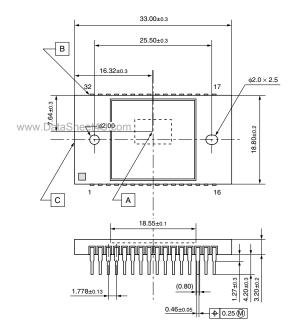
#### Image Sensor Characteristics $T_a = 25^{\circ}C$

Parameter	Parameter		Min	Тур	Max	Unit	Remarks
Saturation output		F value adjust	650	800		mV	at CCD out (Minimum point in image)
Standard output		J chart standard light intensity	140	155		mV	at CCD out
Image lag	Image lag			0		%	Able to be swept out directly to substrate
Vertical smear	Vertical smear			-127	-124	dB	Ratio to standard output 2 MHz driving
Dark shading	H V	60°C, dark condition	_		2	mV	at CCD out
Electronic shutter	1	Specified driving	No abnormality within 1/100 to 1/2000 seconds				

Note) 1. The substrate voltage (Sub 1) should be adjusted to the minimum voltage that would not cause blooming, overflow and injection at image sensor of light input of 1 600 times the standard light intensity.

2. The standard light intensity is the one when the exposure is done at an aperture of F/11 using a light source of 2856K and 920 nt and placing a color temperature conversion filter LB-40 (HOYA) and an IR cutting filter CAW-500S (t = 2.5 mm) in the light path.

- Package Dimensions (unit: mm)
- WDIP032-G-0750A (Lead-free package)



17.55±0.1

- 1. The package center does not meet the center of the effective pixel area. A is the center of the effective pixel area.
- The reference of a vertical direction(V) is the side B. The reference of a horizontal direction(H) is the side C. The reference of a height direction is the package bottom D.
- 3. The rotation precision of the effective pixel area: maximum  $\pm 1.5^{\circ}$
- 4. The distance from the package bottom D to the effective pixel area :  $1.69 \text{ mm} \pm 0.3 \text{ mm}$
- 5. The tilt of the effective pixel area toward the package bottom D : Up to 60  $\mu m$  (D' =  $D_{O} \pm$  max. 0.03 mm)
- 6. The thickness of the seal glass is: 0.7 mm  $\pm$  0.1 mm, and the refractive index: 1.50

## Tolerance: ±0.20 unless otherwise specified

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